

Technical Data Data Sheet N1008, Rev. A **Green Products** 

# SM05S THRU SM10S SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIERS

#### Features:

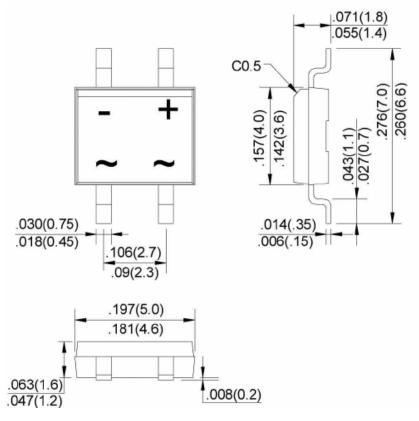
- Rating to 1000V PRV
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Lead tin plated copper
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

### **Mechanical Data:**

Polarity : Symbol molded on body

• Mounting position: Any

### Mechanical Dimensions: In Inches/ mm



**BTS** 

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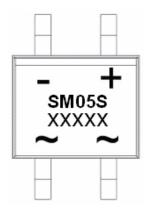
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### **Marking Diagram:**



Where XXXXX is YYWWL

SM05S = Part Name YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	SM05S	SM1S	SM2S	SM4S	SM6S	SM8S	SM10S	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	٧
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward  Rectified Current (Note 1) @Ta=40 ℃	I(AV)	0.8							Α
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load(JEDEC Method)	IFSM	30							Α
Peak Forward Voltage at 0.8A DC	VF	1.1						V	
Maximum DC Reverse Current @TJ=25℃ at Rated DC Bolcking Voltage @TJ=125℃	lR	5.0 500							μA
Typical Junction Capacitance Per Element (Note2)	CJ	15							pF
Typical Thermal Resistance (Note3)	Rejc	75							°C/W
Operating Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	Тѕтс	-55 to +150							$^{\circ}$

NOTES:1.Mounted on P.C. board.

2.Measured at1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to case

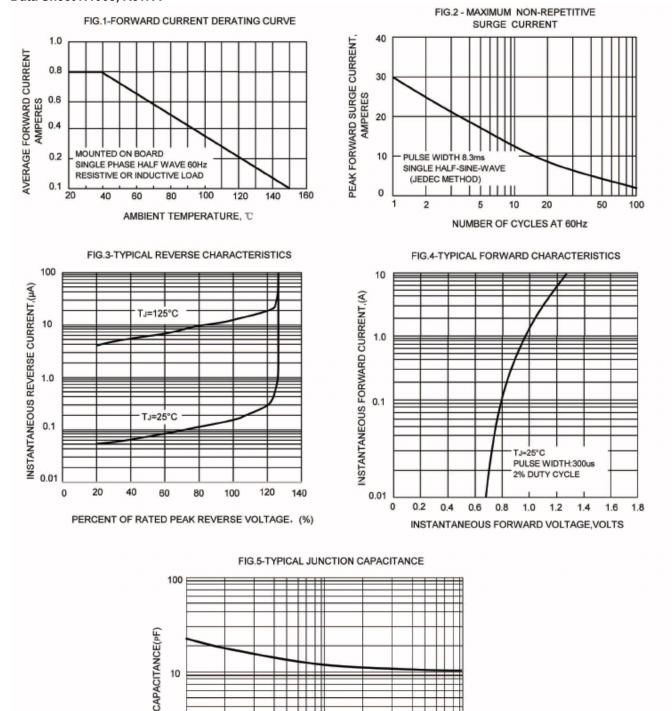
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4 10 REVERSE VOLTAGE, VOLTS 100

TJ=25°C, f=1MHZ

1.0

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